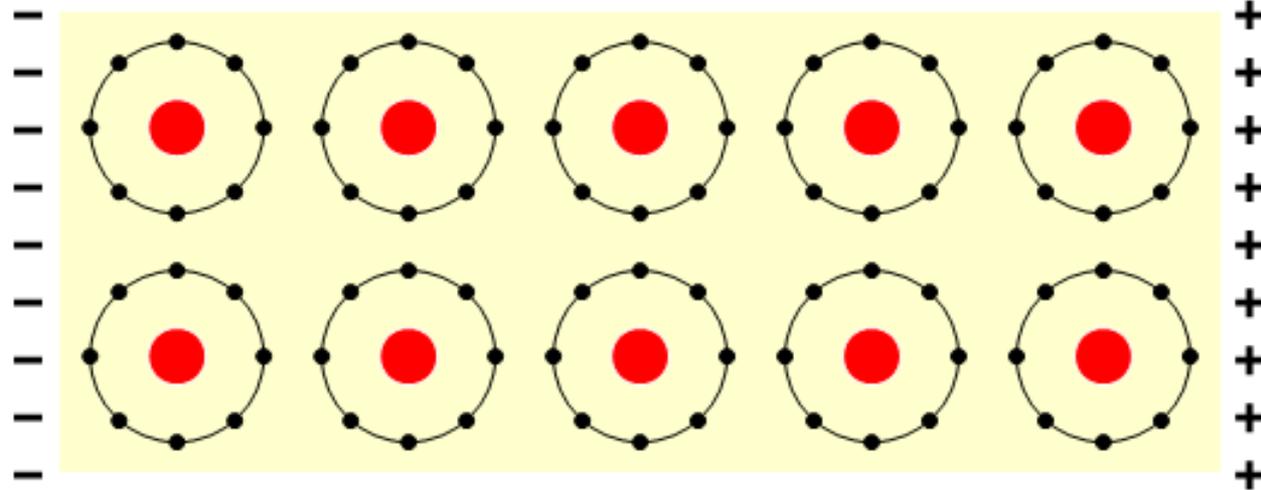


Electronic Materials

- The goal of electronic materials is to **generate and control** the flow of an electric current.
- Electronic materials include:
 1. Conductors: have low resistance which allows electric current flow
 2. Insulators: have high resistance which suppresses electric current flow
 3. Semiconductors: can allow or suppress electrical current flow

Insulators



Insulators have **tightly bound electrons** in their outer shell

These electrons require a **very large amount of energy** to free them for conduction

Let's apply a **potential difference** across the **insulator** above...

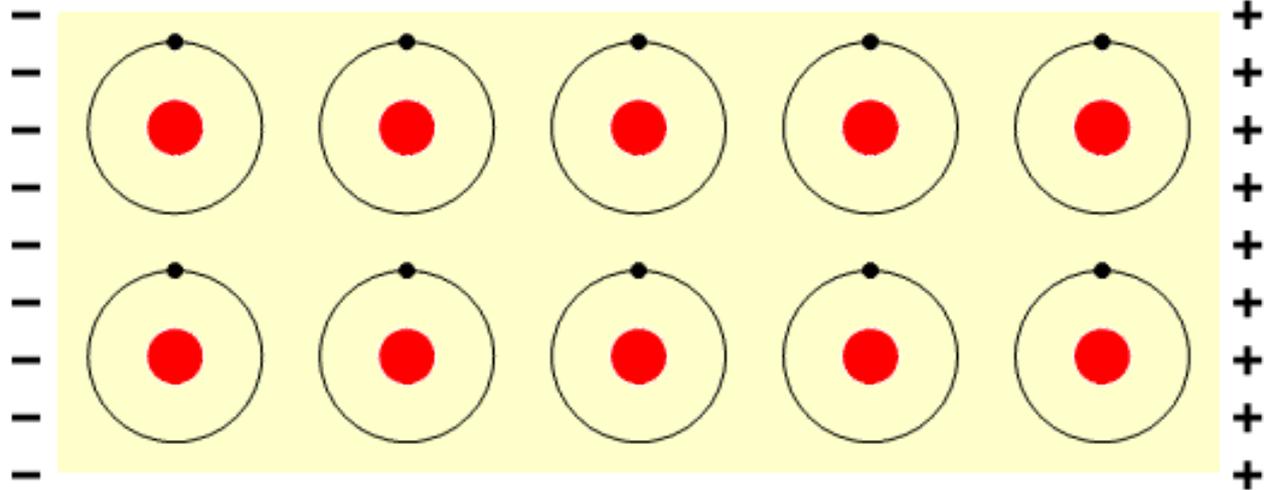
The **force** on each electron is **not enough** to free it from its orbit and the insulator does not **conduct**

Insulators are said to have a **high resistivity / resistance**

Insulators

- Insulators have a high resistance so current does not flow in them.
- Good insulators include:
 - Glass, ceramic, plastics, & wood
- Most insulators are compounds of several elements.
- The atoms are tightly bound to one another so electrons are difficult to strip away for current flow.

Conductors



Conductors have **loosely bound electrons** in their outer shell
These electrons require a **small amount of energy** to free them
for conduction

Let's apply a **potential difference** across the **conductor** above...

The **force** on each electron is enough to **free it** from its orbit
and it can jump from atom to atom – the conductor **conducts**

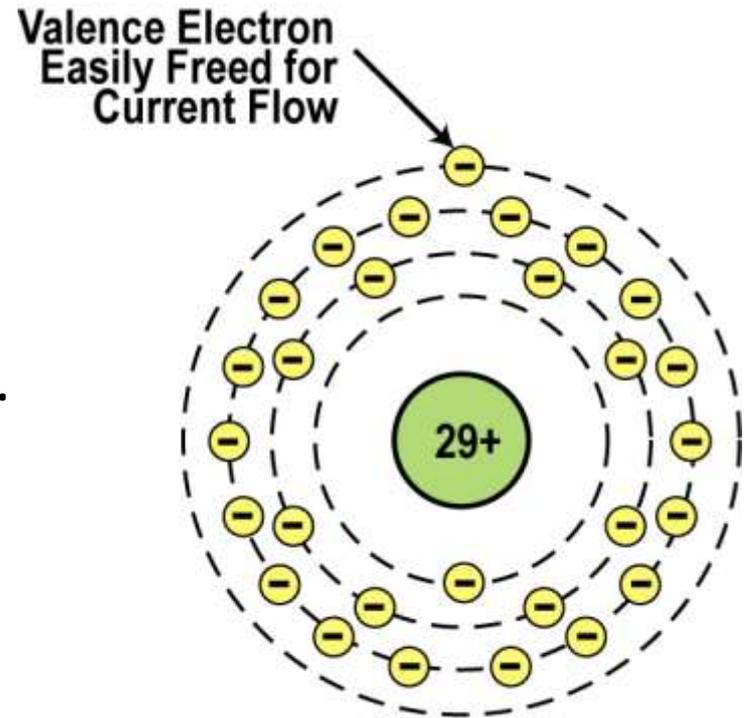
Conductors are said to have a **low resistivity / resistance**

Conductors

- Good conductors have low resistance so electrons flow through them with ease.
- **Best** element conductors include:
 - Copper, silver, gold, aluminum, & nickel
- Alloys are also good conductors:
 - Brass & steel
- Good conductors can also be liquid:
 - Salt water

Conductor Atomic Structure

- The atomic structure of good conductors usually includes only one electron in their outer shell.
 - It is called a valence electron.
 - It is easily stripped from the atom, producing current flow.



**Copper
Atom**

Semiconductors

- A material whose properties are such that it is not quite a conductor, not quite an insulator.
- **Semiconductors** have a resistivity/resistance **between** that of conductors and insulators.
- Their electrons are **not free to move** but a little energy will free them for conduction
- Some common semiconductors
 - elemental
 - Si - Silicon (most common)
 - Ge - Germanium
 - compound
 - GaAs - Gallium arsenide
 - GaP - Gallium phosphide
 - AlAs - Aluminum arsenide
 - AlP - Aluminum phosphide
 - InP - Indium Phosphide

(The resistance of a semiconductor decreases as the temperature increases.)

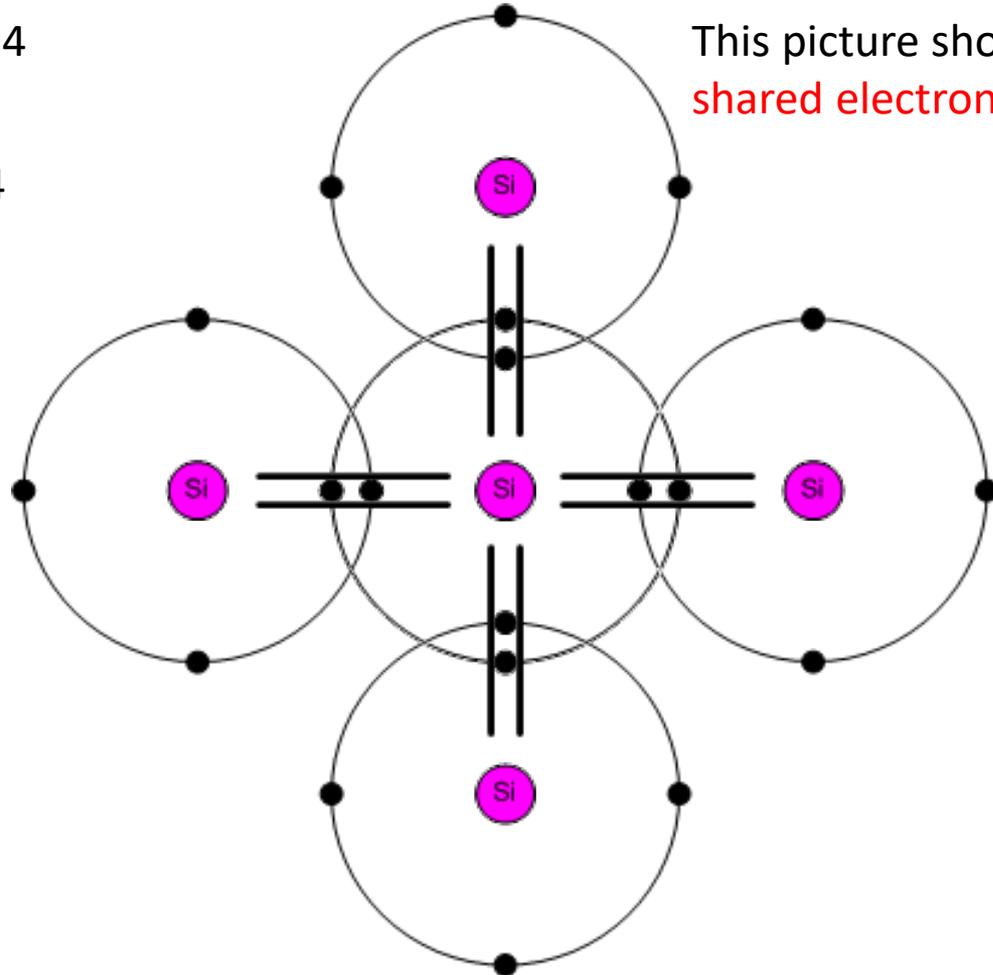
The Silicon, Si, Atom

Silicon has a **valency of 4** i.e. 4 electrons in its **outer shell**

Each silicon atom **shares** its 4 outer electrons with 4 neighbouring atoms

These shared electrons – **bonds** – are shown as **horizontal** and **vertical** lines between the atoms

This picture shows the **shared electrons**

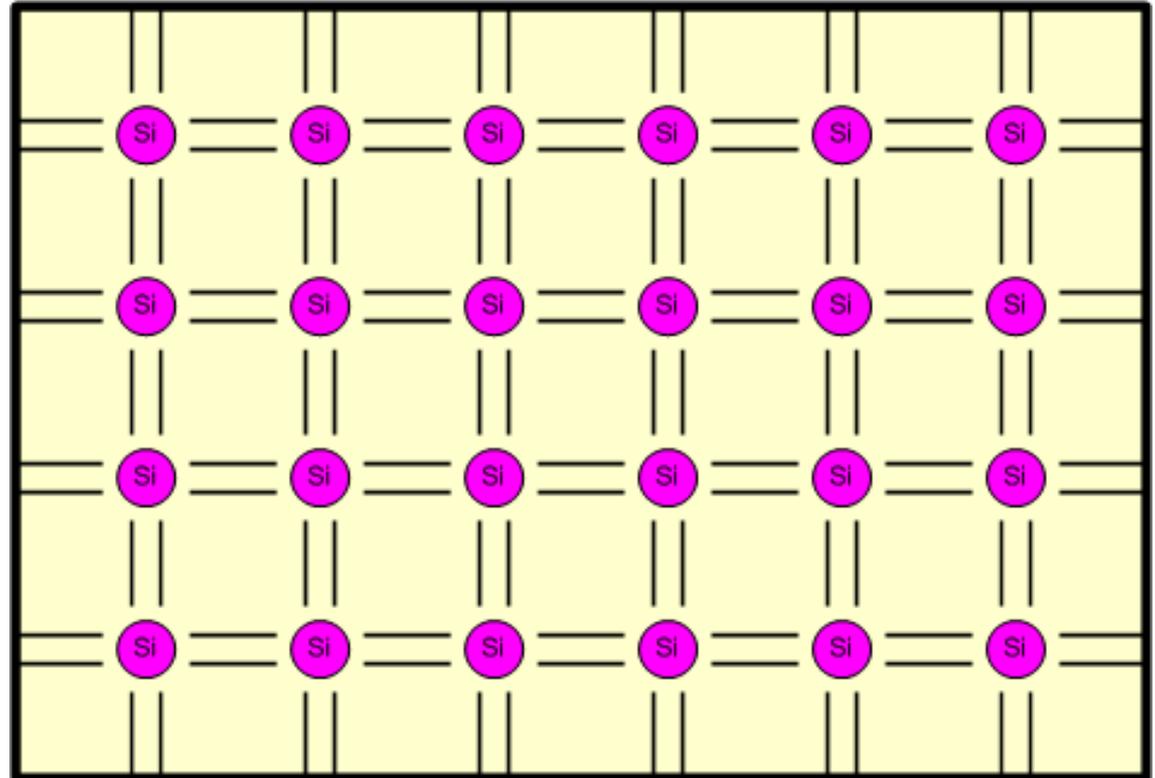


Silicon – the crystal lattice

If we **extend** this arrangement throughout a piece of silicon...

We have the **crystal lattice** of silicon

This is how silicon looks when it is **cold**



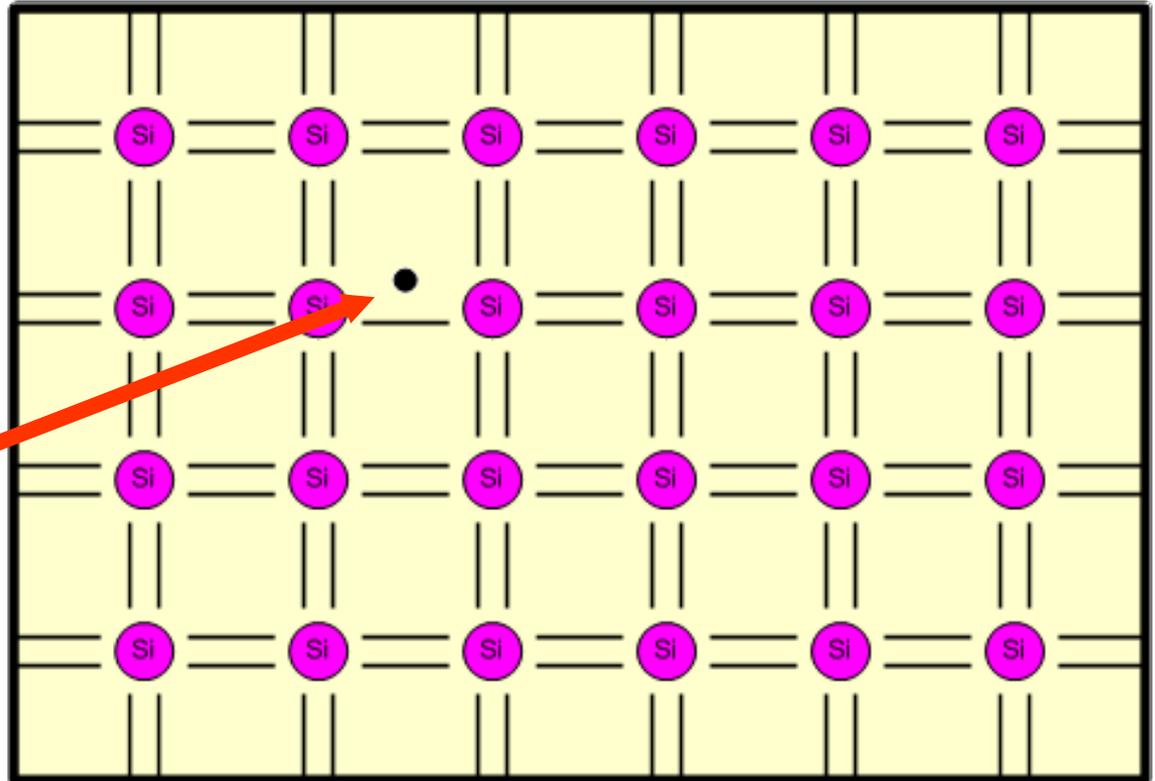
It has no **free** electrons – it cannot **conduct** electricity – therefore it behaves like an **insulator**

Electron Movement in Silicon

However, if we apply a little **heat** to the silicon....

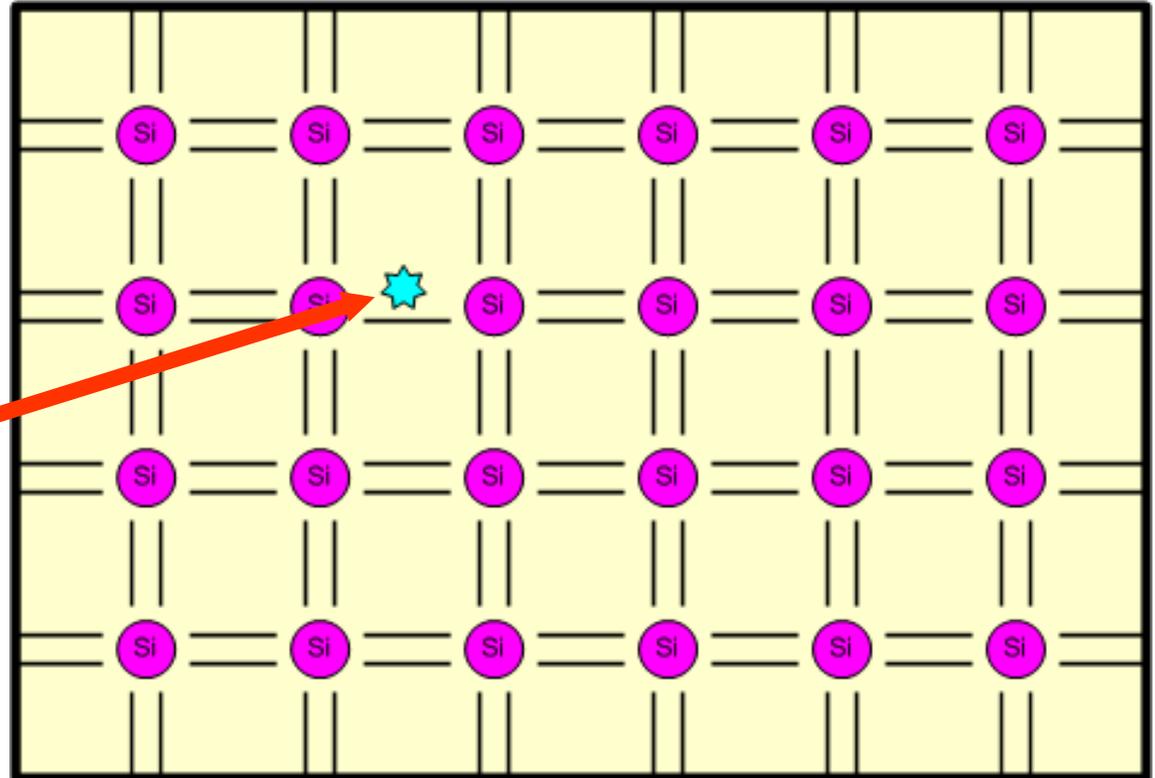
An electron may gain enough **energy** to break free of its bond...

It is then **available for conduction** and is free to travel throughout the material



Hole Movement in Silicon

Let's take a closer look at what the electron has left behind



There is a **gap** in the bond – what we call a **hole**



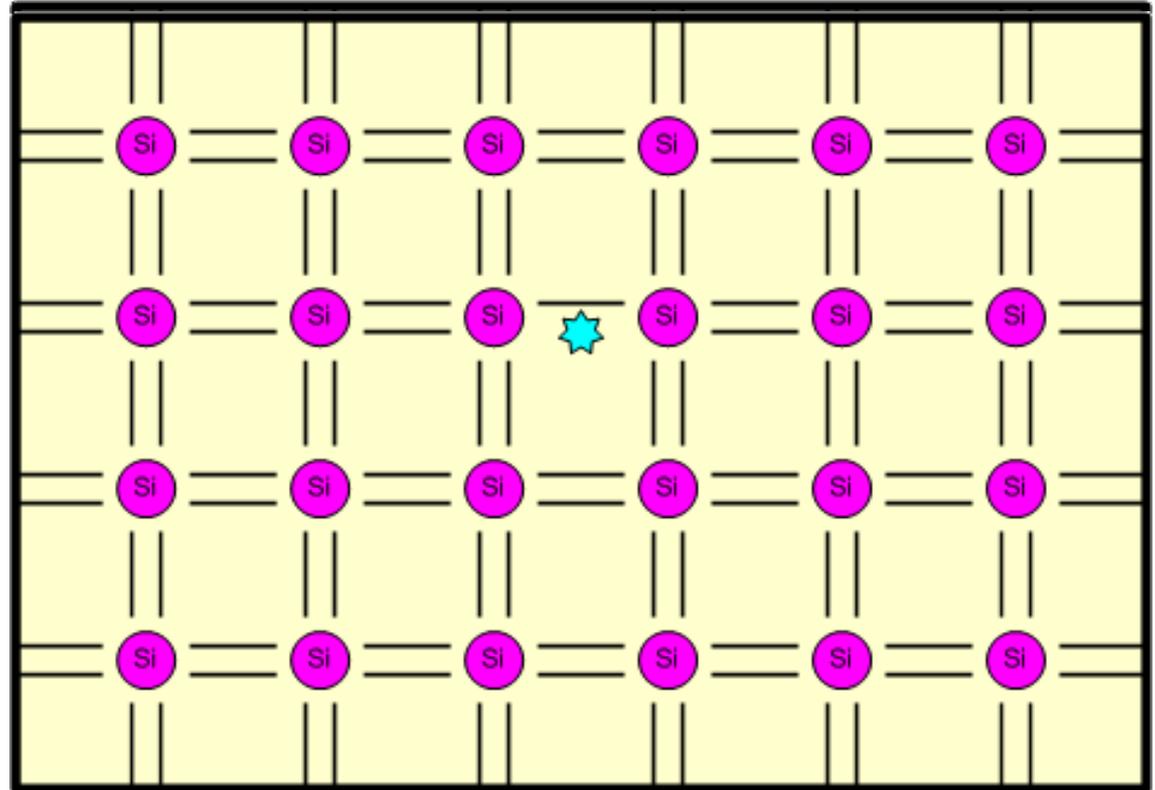
Hole Movement in Silicon

This hole can also **move**...

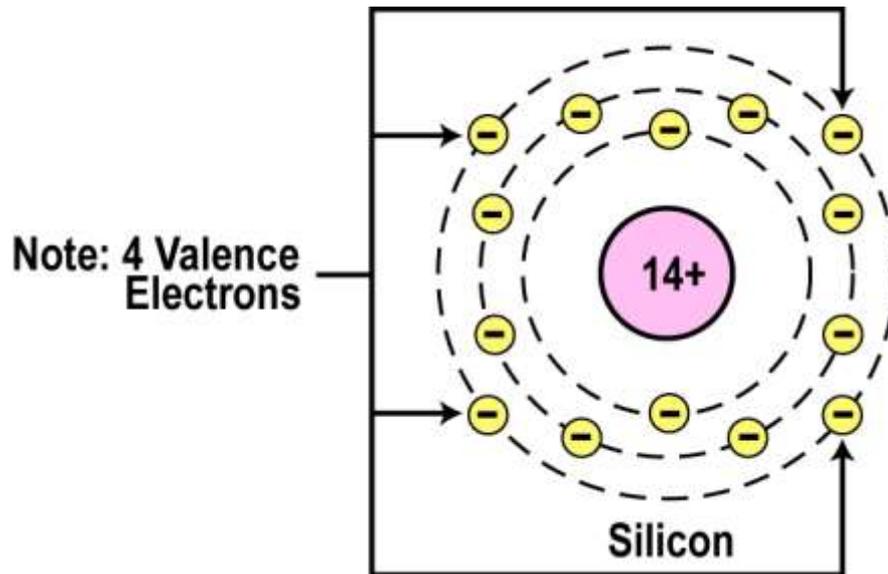
An electron – in a nearby bond – may **jump** into this hole...

Effectively causing the hole to **move**...

Like this...



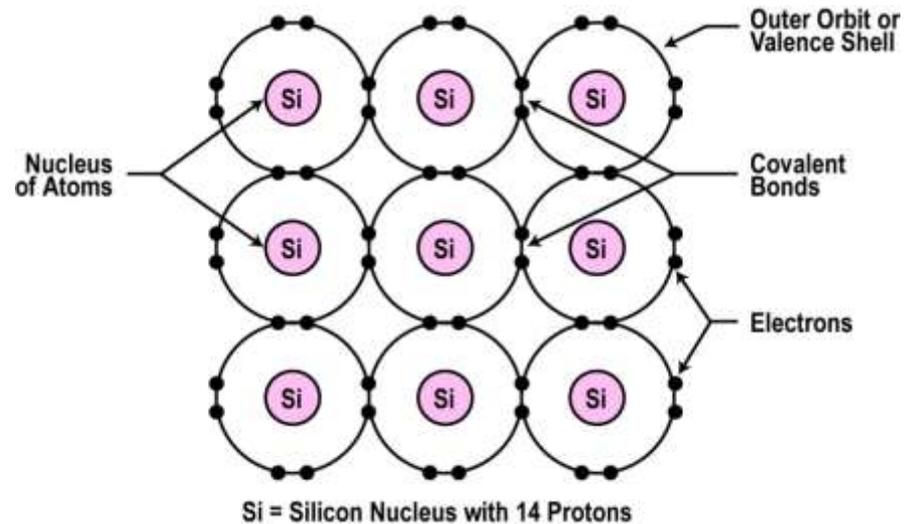
Semiconductor Valence Orbit



- The main characteristic of a semiconductor element is that it has four electrons in its outer or valence orbit.

Crystal Lattice Structure

- The unique capability of semiconductor atoms is their ability to link together to form a physical structure called a crystal lattice.
- The atoms link together with one another sharing their outer electrons.
- These links are called covalent bonds.



**2D Crystal Lattice
Structure**

Semiconductors

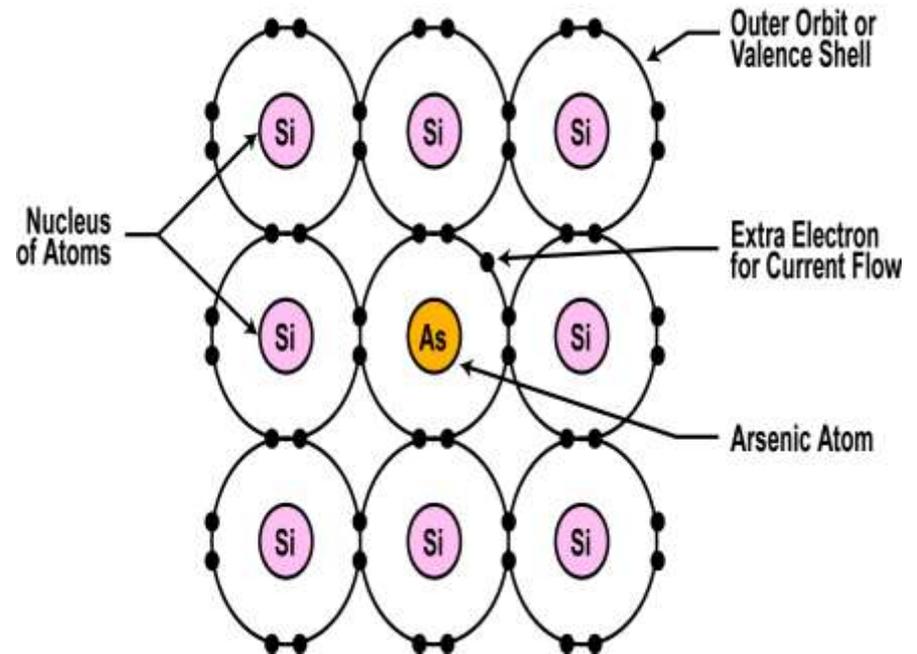
- An **intrinsic** semiconductor, also called an **undoped** semiconductor or i-type semiconductor, is a pure semiconductor without any significant dopant species present.
- An **extrinsic** semiconductor is a semiconductor that has been **doped**.

Doping

- Relying on **heat** or **light** for conduction does not make for **reliable** electronics
- To make the semiconductor conduct electricity, other atoms called **impurities** must be added.
- “Impurities” are different elements.
- This process is called **doping**.

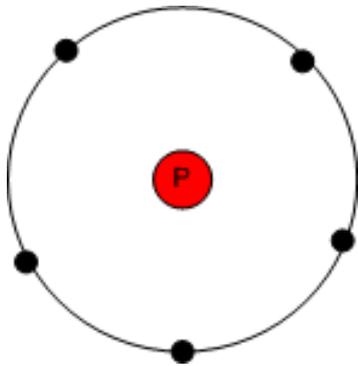
Semiconductors can be Conductors

- An impurity, or element like arsenic, has 5 valence electrons.
- Adding arsenic (doping) will allow four of the arsenic valence electrons to bond with the neighboring silicon atoms.
- The one electron left over for each arsenic atom becomes available to conduct current flow.

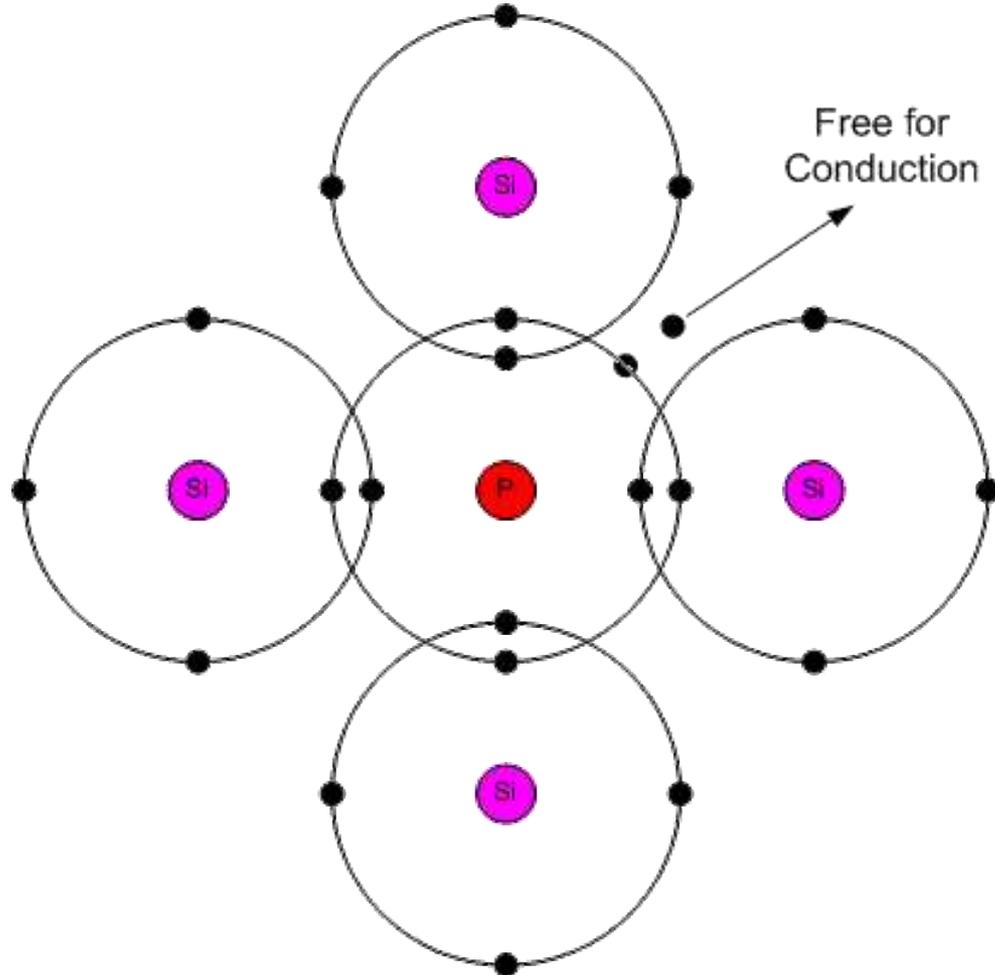


The Phosphorus Atom

Phosphorus is **number 15**
in the periodic table



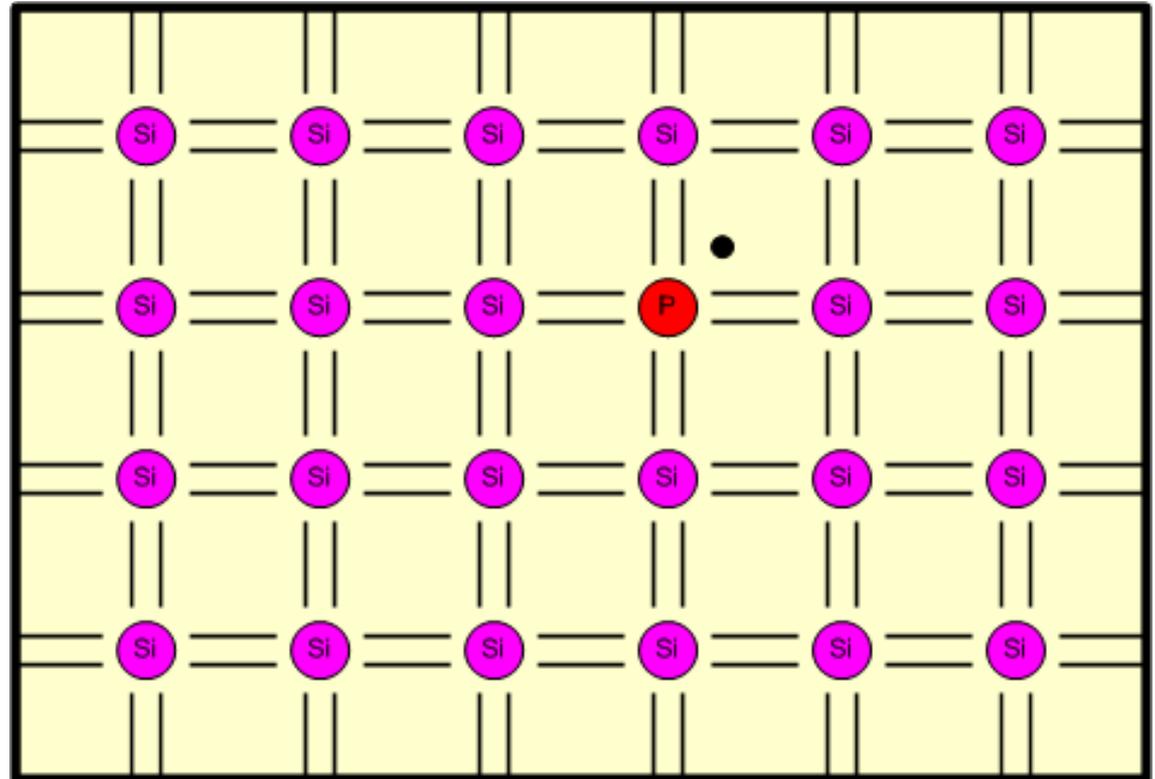
It has **15 protons** and **15 electrons** – 5 of these electrons are in its outer shell



Doping – Making n-type Silicon

Suppose we **remove** a **silicon** atom from the crystal lattice...

and **replace** it with a **phosphorus** atom



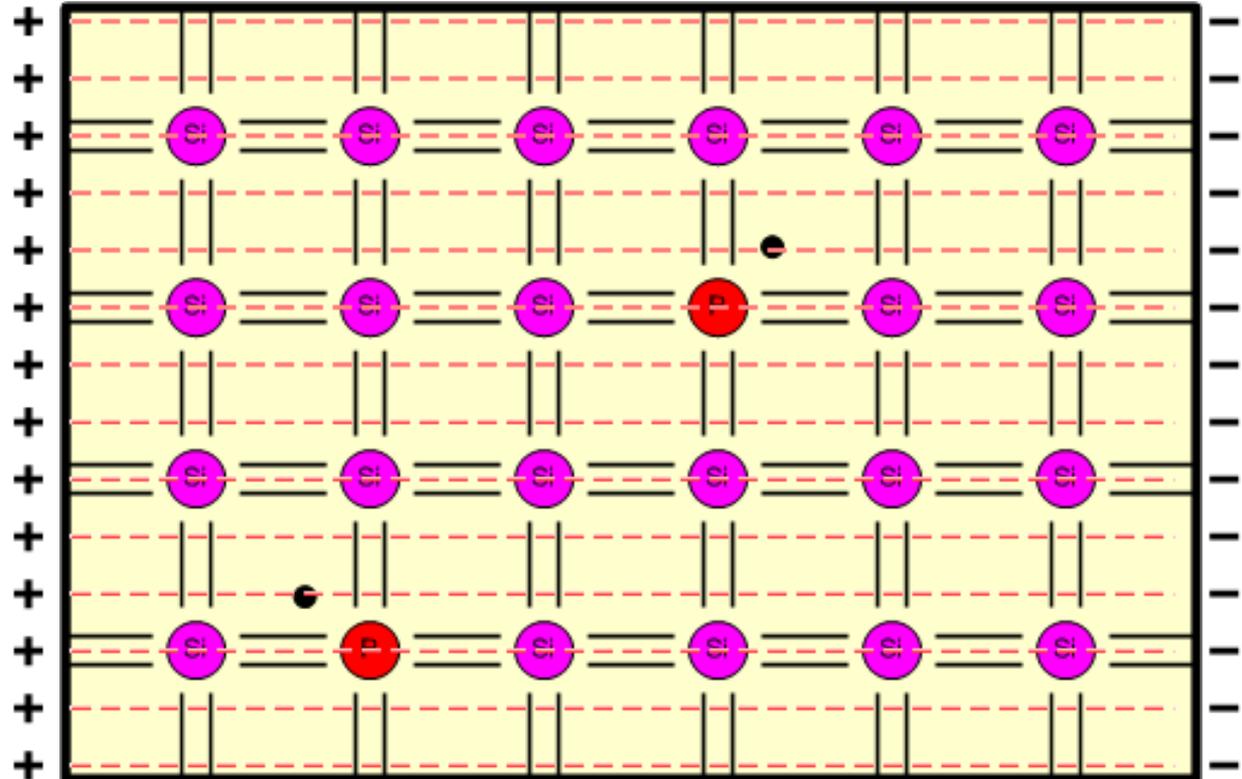
We now have an electron that is **not bonded** – it is thus **free** for **conduction**

Doping – Making n-type Silicon

Let's **remove** another **silicon** atom...

and **replace** it with a **phosphorus** atom

As **more electrons** are available for conduction we have **increased** the **conductivity** of the material



Phosphorus is called the **dopant**

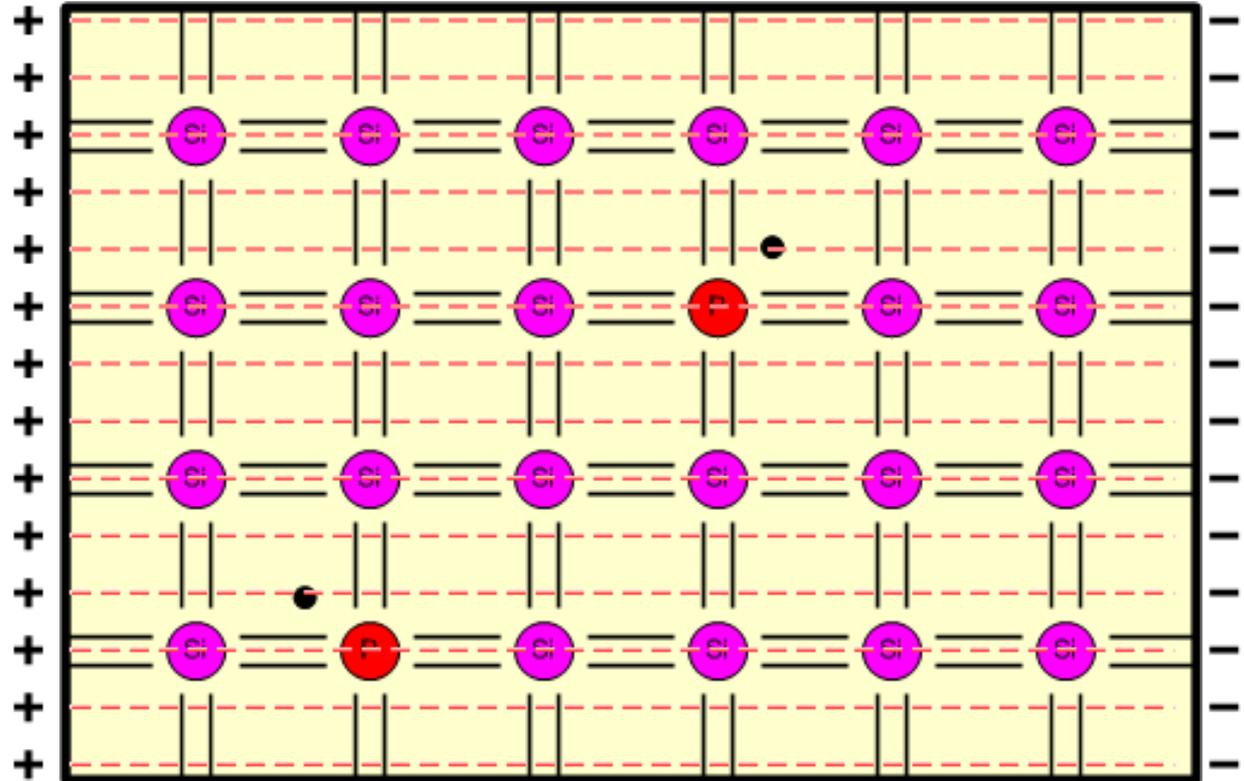
If we now apply a **potential difference** across the silicon...

Extrinsic Conduction – n-type Silicon

A **current** will flow

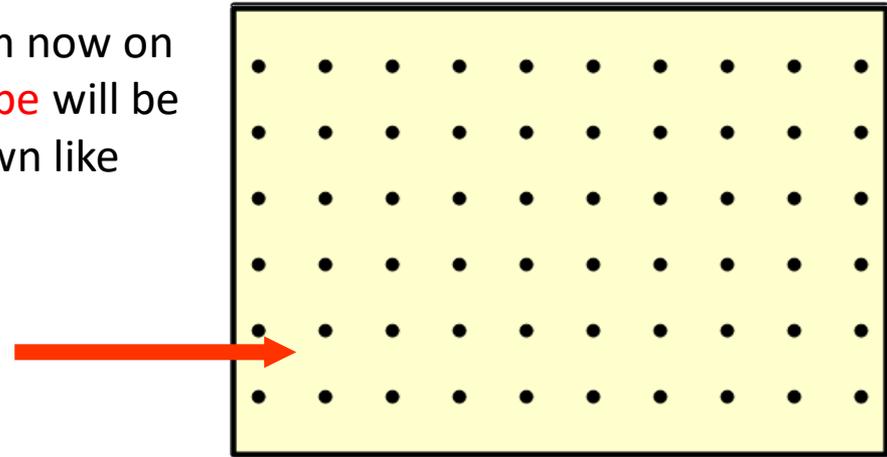
Note:

The **negative electrons** move towards the **positive terminal**



N-type Silicon

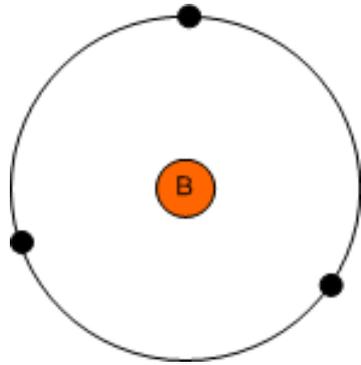
From now on
n-type will be
shown like
this.



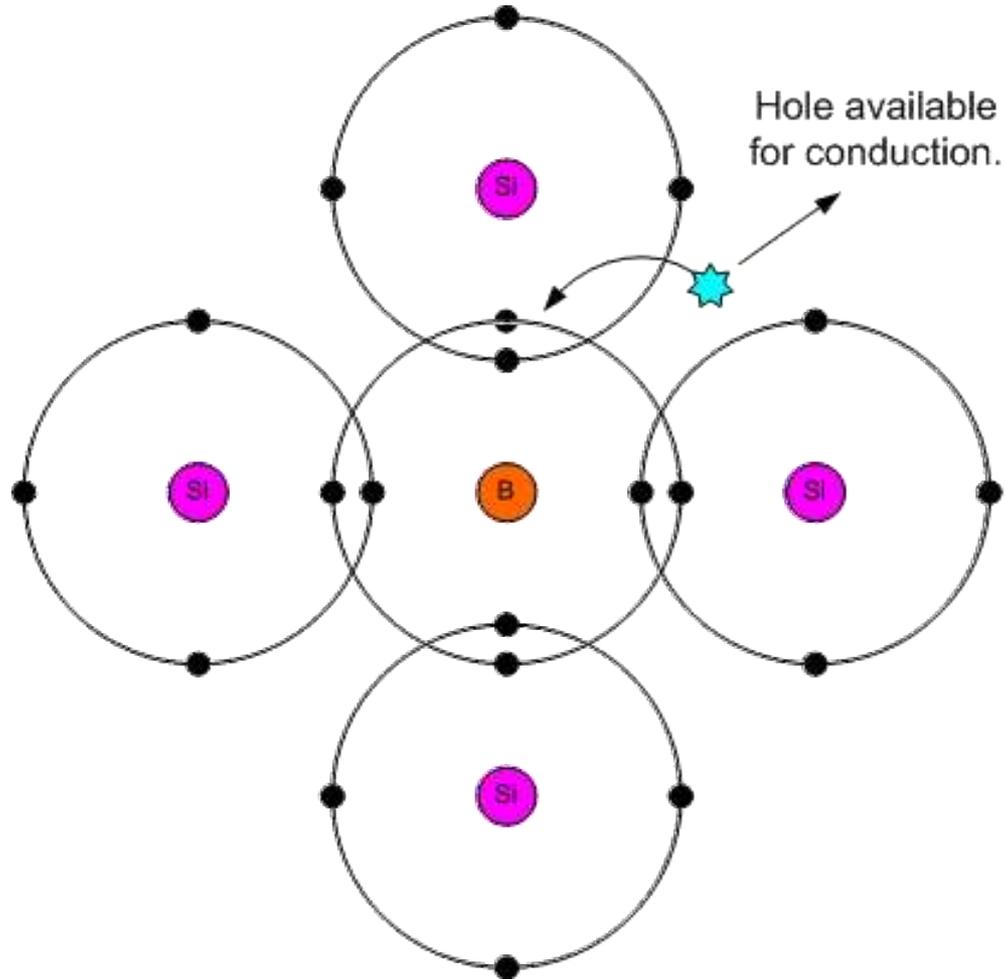
- This type of silicon is called **n-type**
- This is because the **majority charge carriers** are **negative** electrons
- A small number of **minority charge carriers** – holes – will exist due to **electrons-hole pairs** being created in the silicon atoms due to **heat**
- The silicon is still **electrically neutral** as the number of **protons** is **equal** to the number of **electrons**

The Boron Atom

Boron is **number 5** in the periodic table



It has **5 protons** and **5 electrons** – **3** of these electrons are in its outer shell

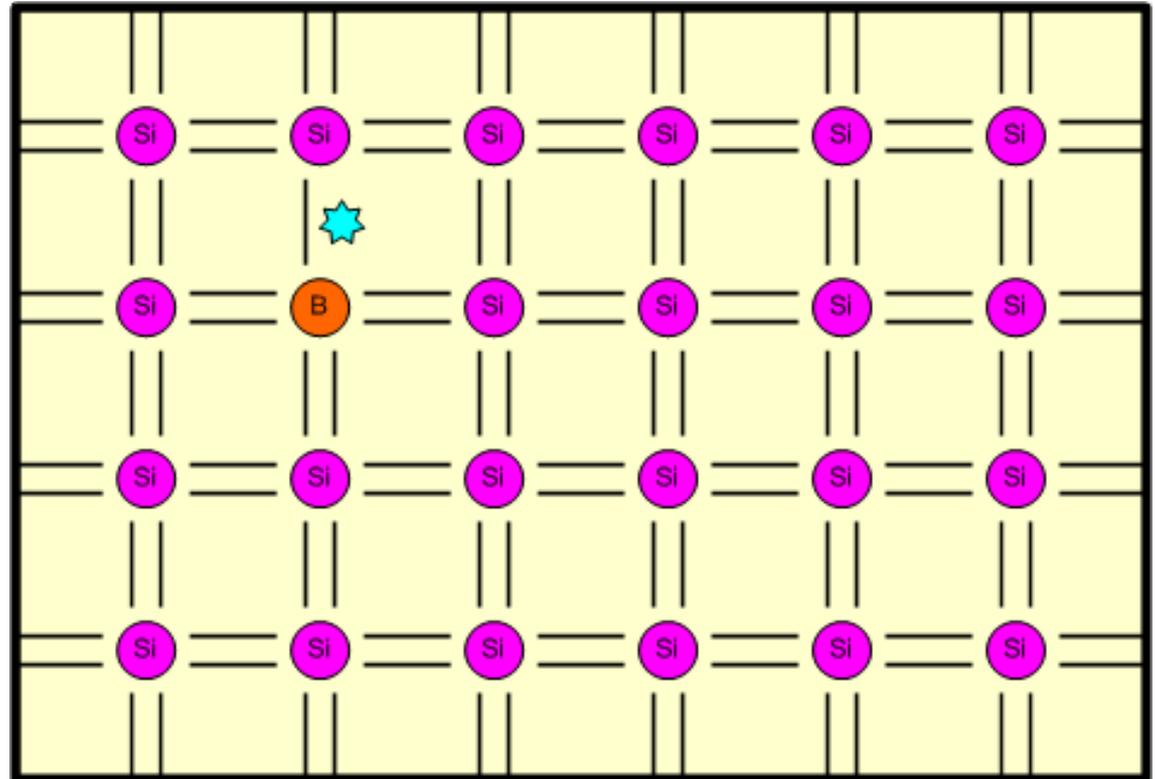


Doping – Making p-type Silicon

As before, we **remove** a **silicon atom** from the crystal lattice...

This time we **replace** it with a **boron atom**

Notice we have a hole in a **bond** – this **hole** is thus **free** for **conduction**

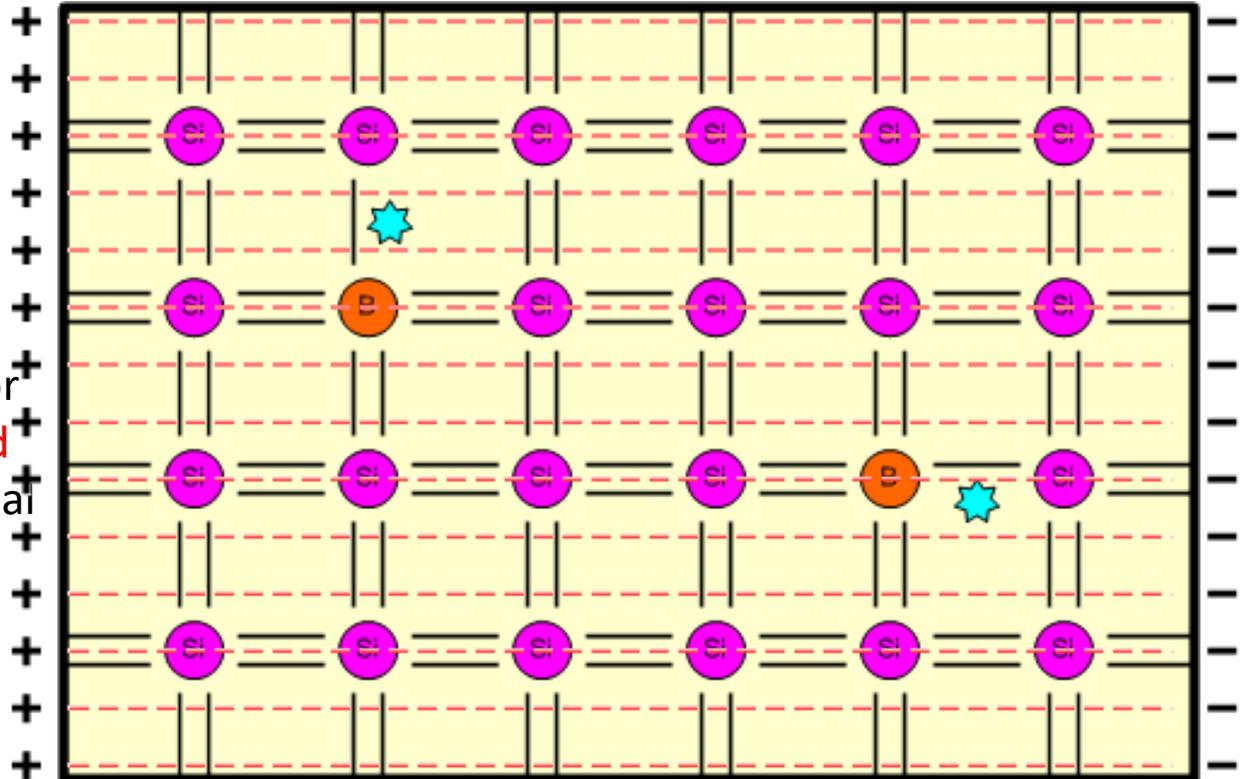


Doping – Making p-type Silicon

Let's **remove** another **silicon** atom...

and **replace** it with another **boron** atom

As **more holes** are available for conduction we have **increased** the **conductivity** of the material

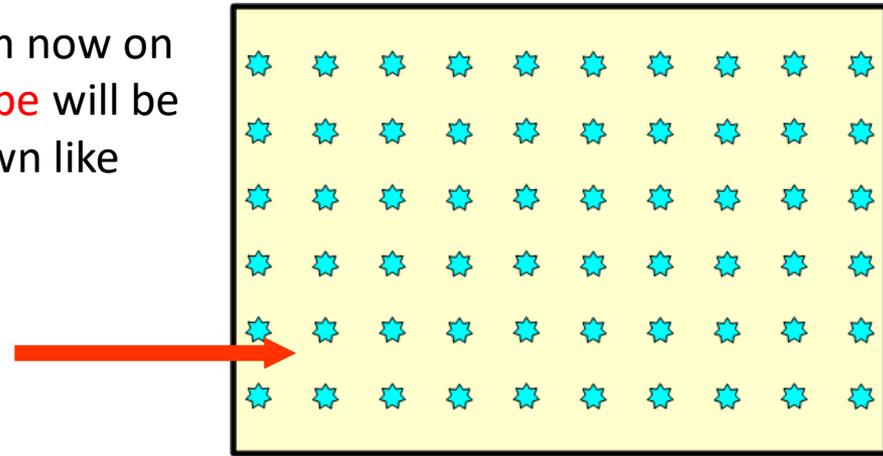


Boron is the **dopant** in this case

If we now apply a **potential difference** across the silicon...

P-type Silicon

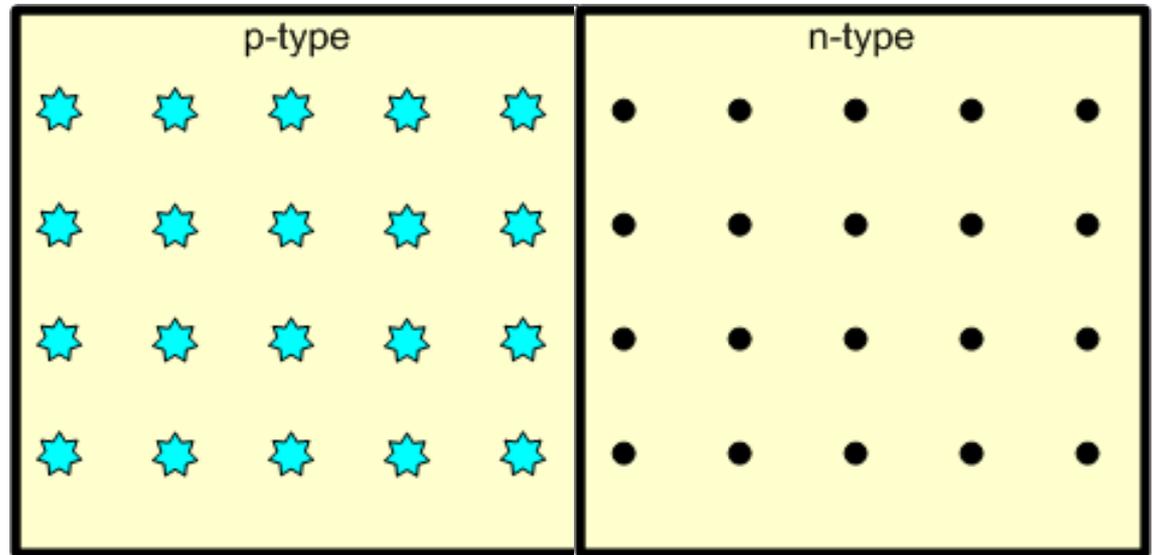
From now on
p-type will be
shown like
this.



- This type of silicon is called **p-type**
- This is because the **majority charge carriers** are **positive holes**
- A small number of **minority charge carriers** – electrons – will exist due to **electrons-hole pairs** being created in the silicon atoms due to **heat**
- The silicon is still **electrically neutral** as the number of **protons** is **equal** to the number of **electrons**

The p-n Junction

Suppose we join a piece of **p-type** silicon to a piece of **n-type** silicon



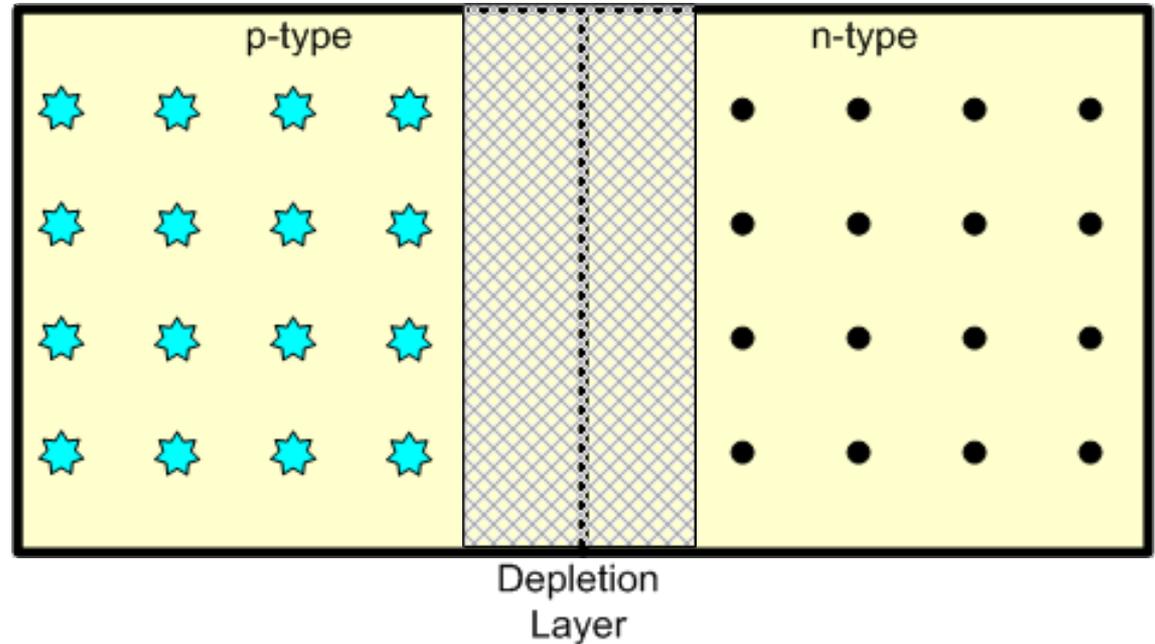
We get what is called a **p-n junction**

Remember – both pieces are electrically neutral

The p-n Junction

When initially joined electrons from the n-type **migrate** into the p-type – less **electron density** there

When an electron **fills** a hole – both the electron and hole **disappear** as the **gap** in the **bond** is filled

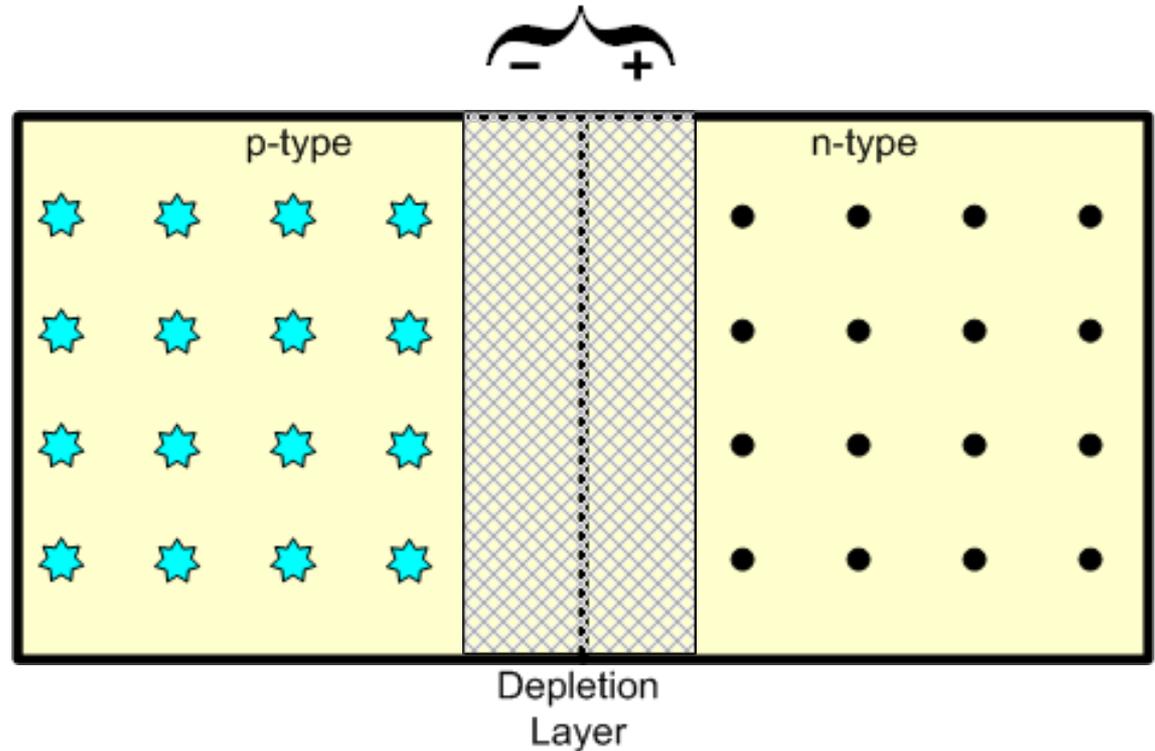


This leaves a region with **no free charge carriers** – the **depletion layer** – this layer acts as an **insulator**

The p-n Junction

As the **p-type** has **gained** electrons – it is left with an overall **negative** charge...

As the **n-type** has **lost** electrons – it is left with an overall **positive** charge...



Therefore there is a voltage across the junction – the **junction voltage** – for silicon this is approximately 0.6 V

The Reverse Biased P-N Junction

Take a **p-n junction**

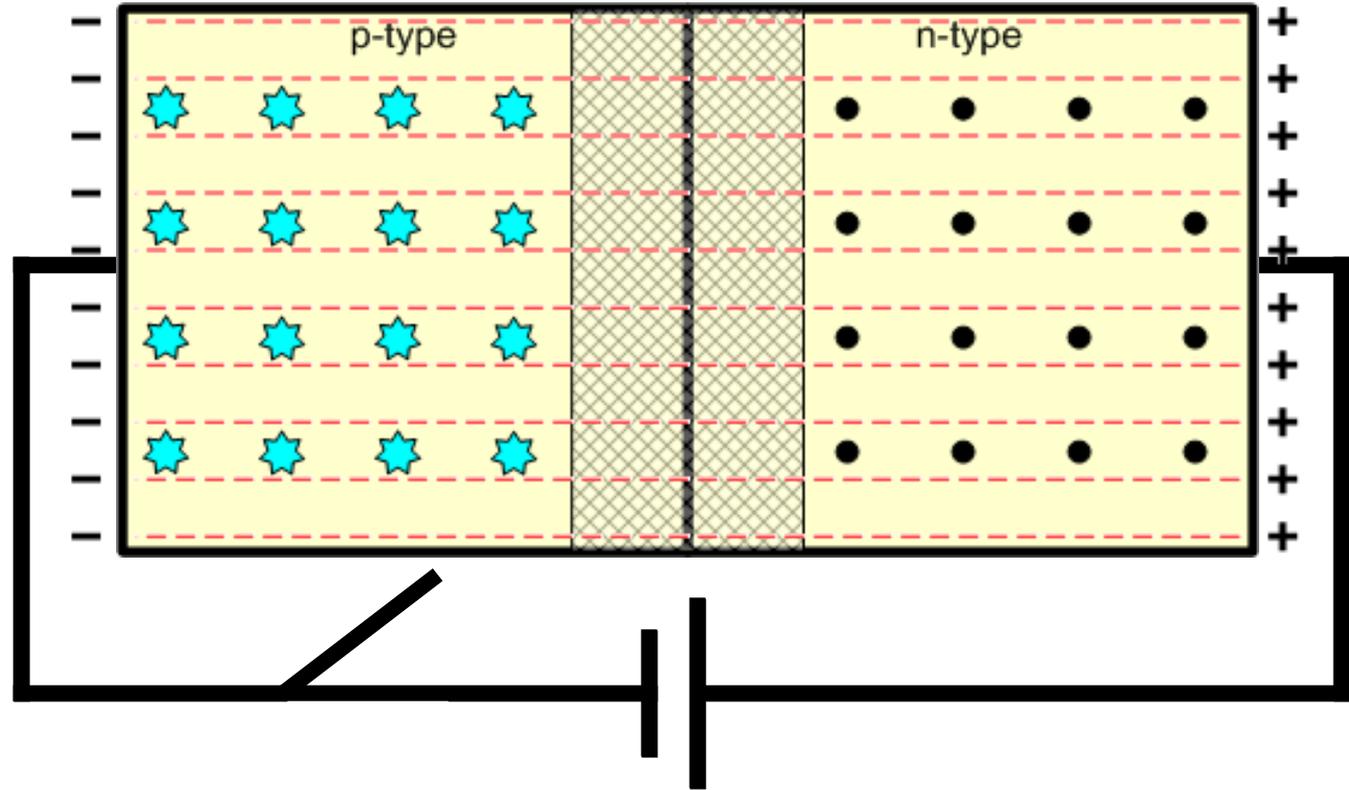
Apply a voltage across it with the

p-type negative

n-type positive

Close the switch

The voltage sets up an **electric field** throughout the junction

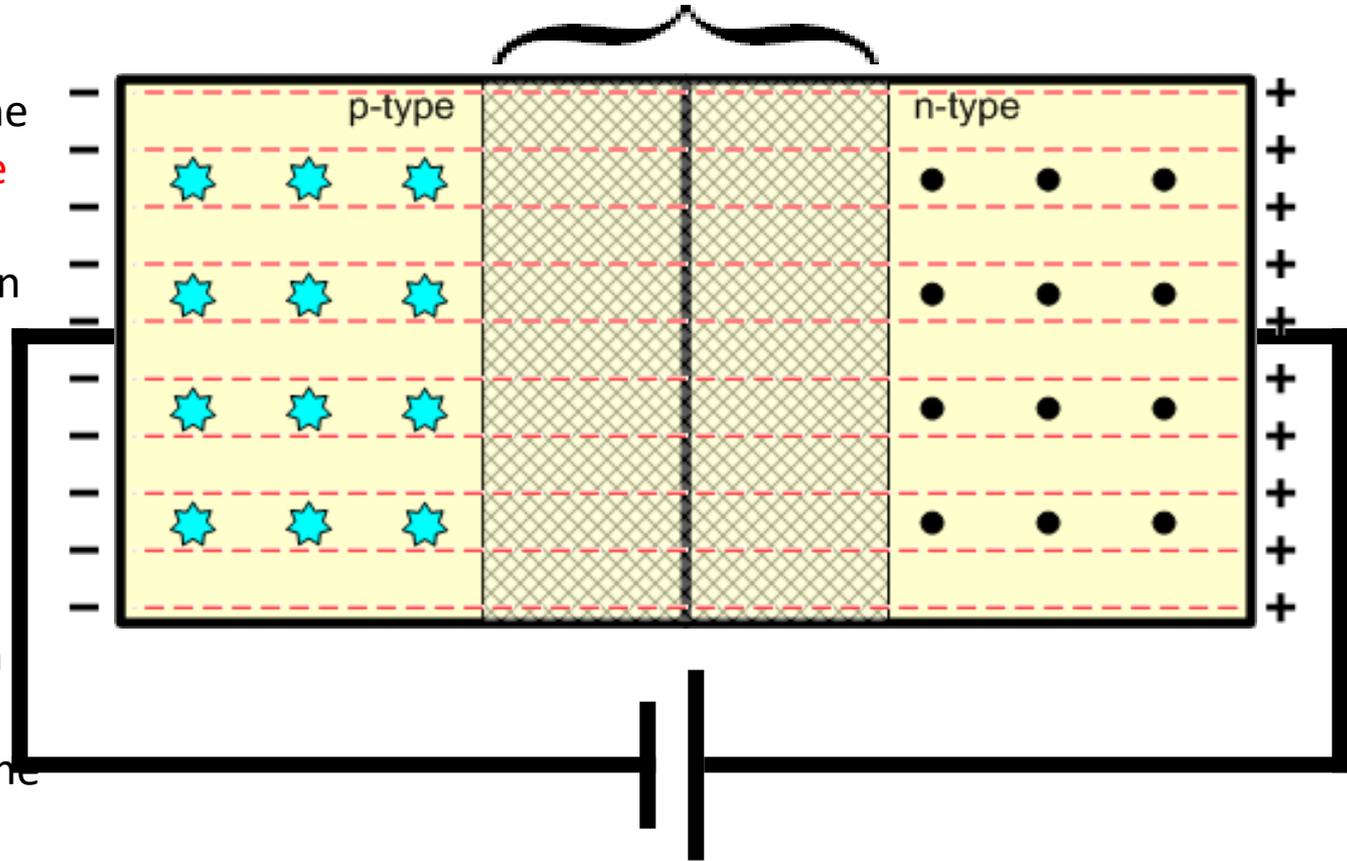


The junction is said to be **reverse – biased**

The Reverse Biased P-N Junction

Negative electrons in the n-type feel an attractive force which pulls them away from the depletion layer

Positive holes in the p-type also experience an attractive force which pulls them away from the depletion layer



Thus, the depletion layer (**INSULATOR**) is **widened** and **no current** flows through the **p-n junction**

The Forward Biased P-N Junction

Take a **p-n junction**

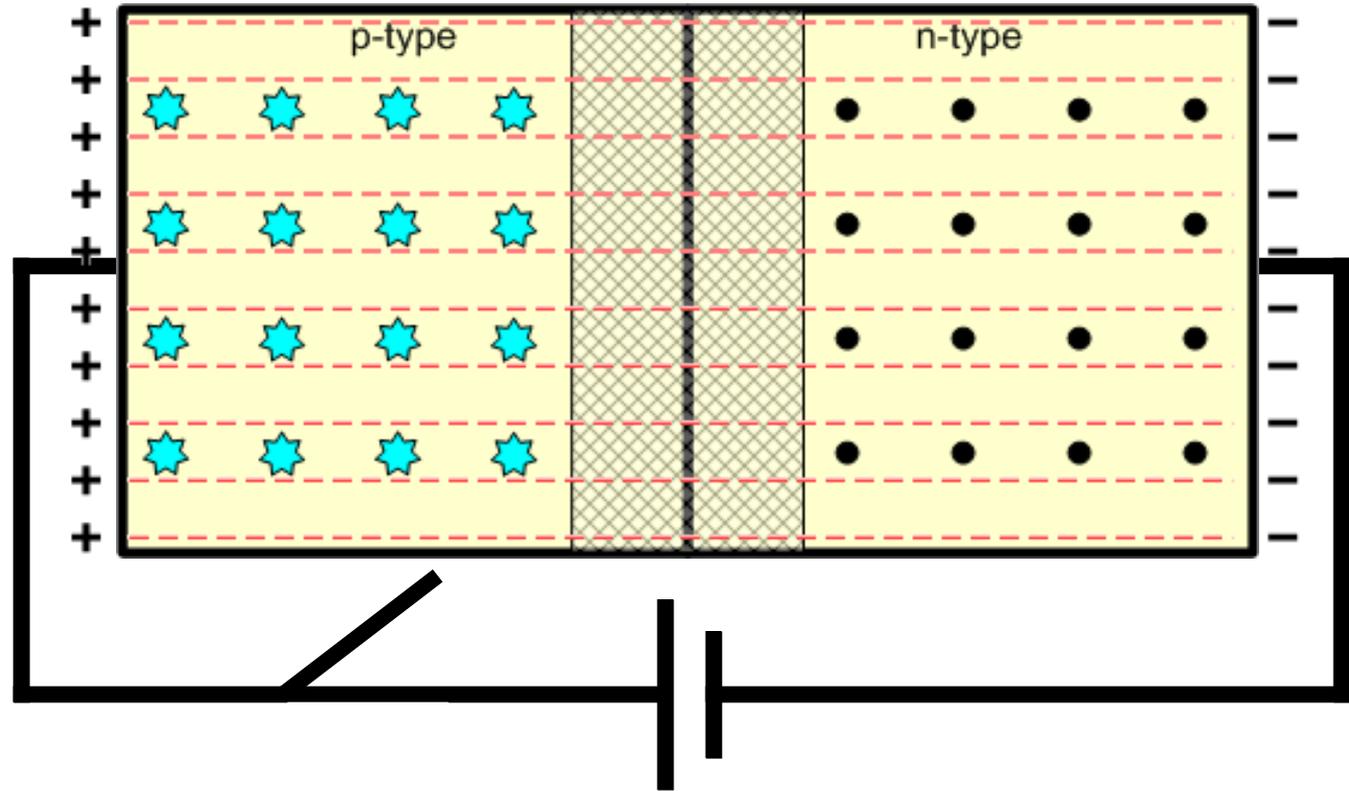
Apply a voltage across it with the

p-type positive

n-type negative

Close the switch

The voltage sets up an **electric field** throughout the junction

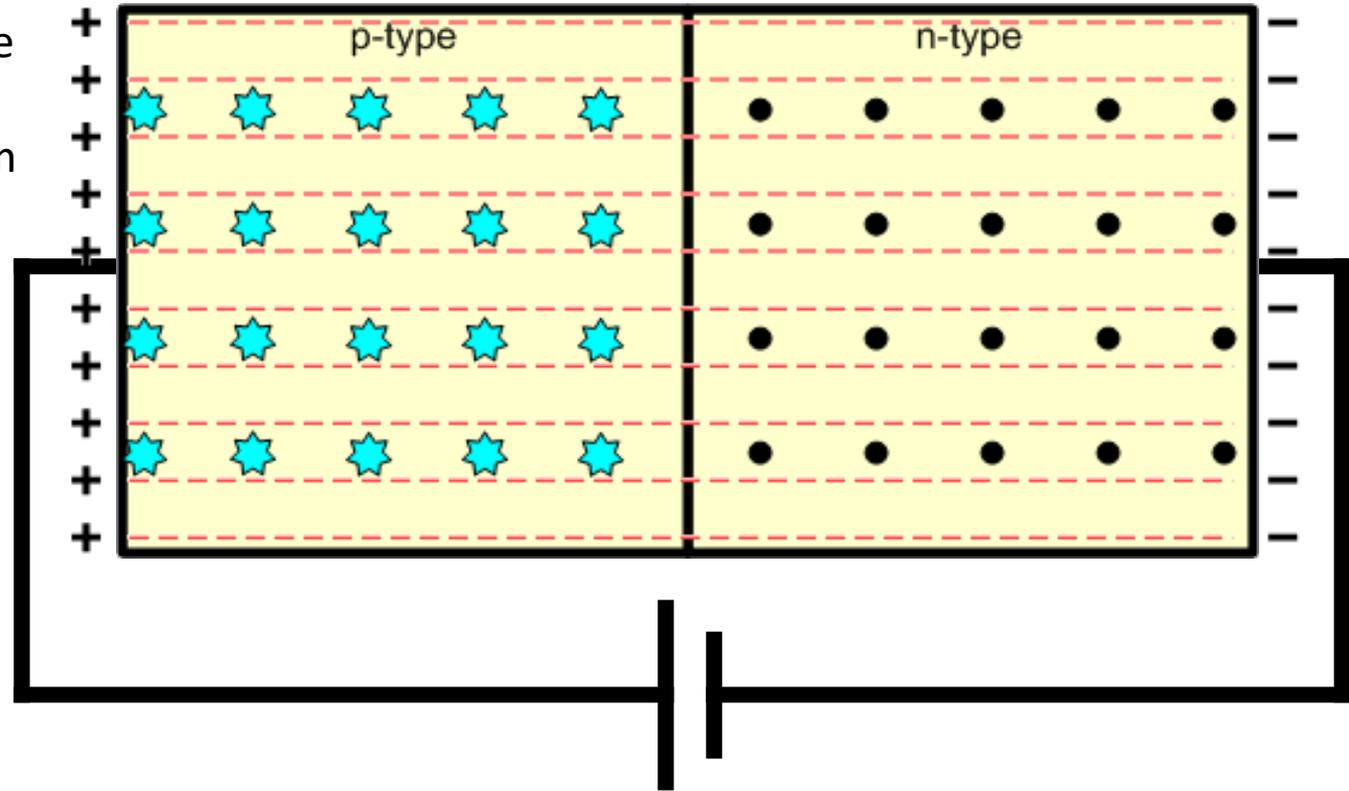


The junction is said to be **forward – biased**

The Forward Biased P-N Junction

Negative electrons in the n-type feel a repulsive force which pushes them into the depletion layer

Positive holes in the p-type also experience a repulsive force which pushes them into the depletion layer



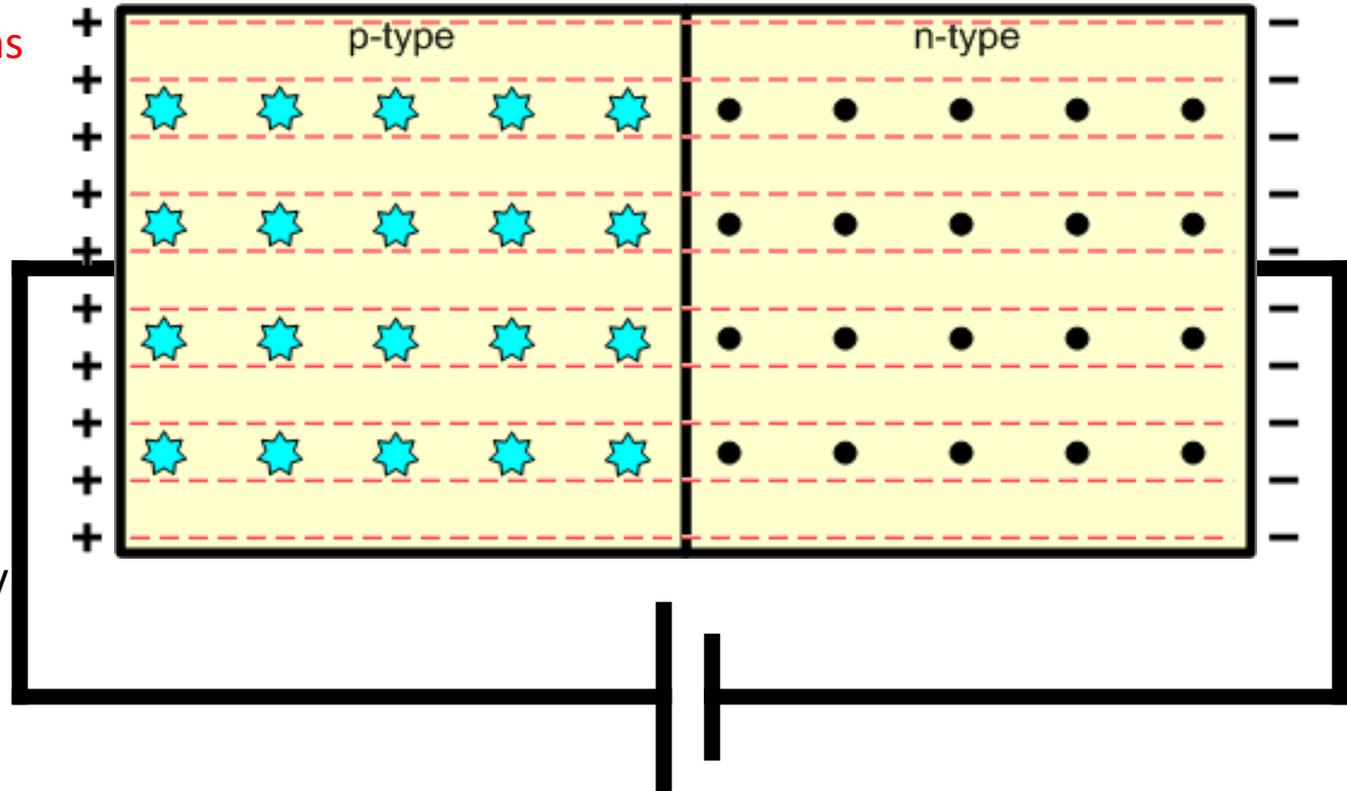
Therefore, the depletion layer is eliminated and a current flows through the p-n junction

The Forward Biased P-N Junction

At the junction **electrons** fill holes

Both **disappear** as they are no longer free for conduction

They are **replenished** by the external cell and **current flows**



This continues as long as the external voltage is **greater than** the junction voltage i.e. **0.6 V**

The Forward Biased P-N Junction

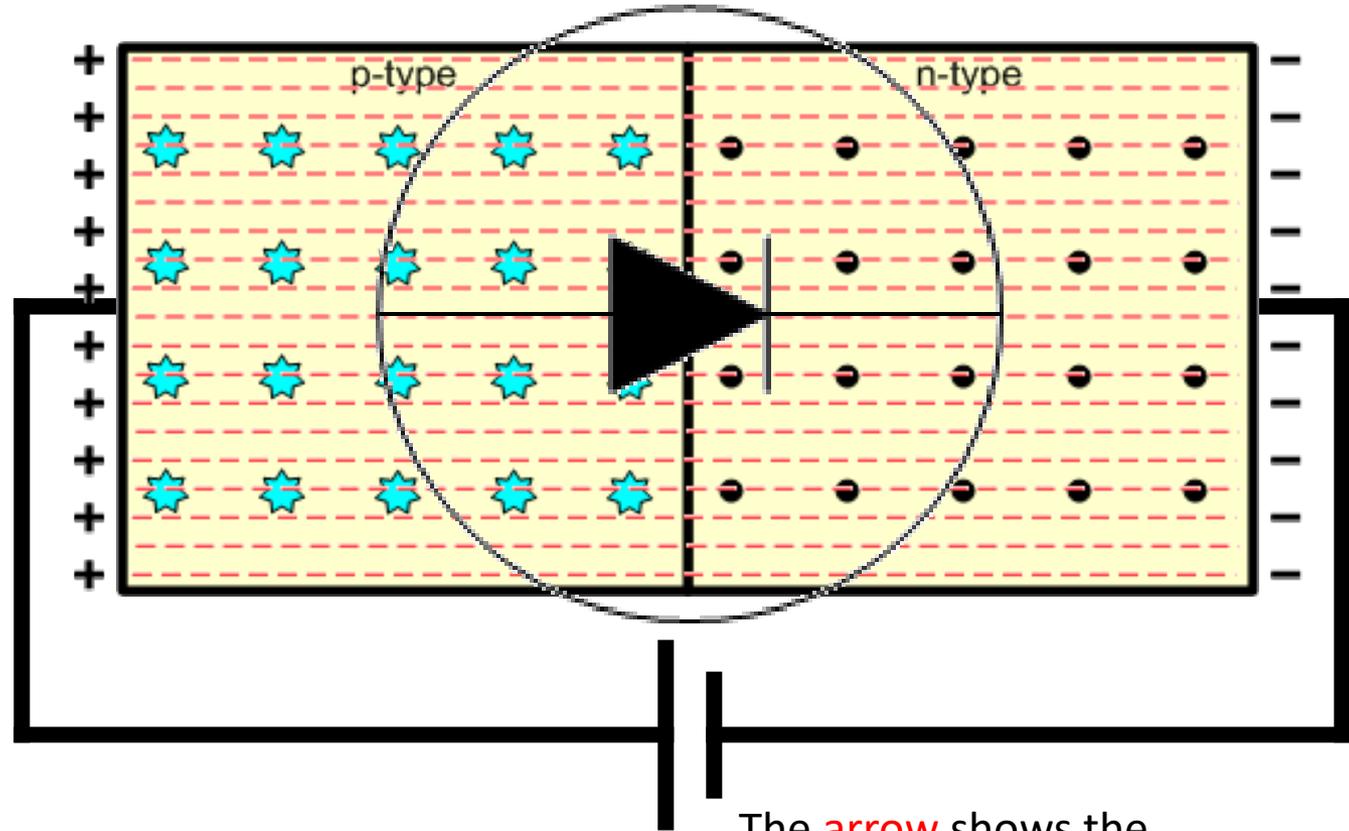
If we apply a **higher** voltage...

The electrons feel a greater force and move **faster**

The current will be **greater** and will look like

this....

The **p-n junction** is called a **DIODE** and is represented by the symbol...



The **arrow** shows the **direction** in which it **conducts current**

